

TC74HC4514AP

4 - TO - 16 LINE DECODER / LATCH

The TC74HC4514A are high speed CMOS 4 - LINE TO 16 - LINE DECODER WITH LATCHED INPUTs fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

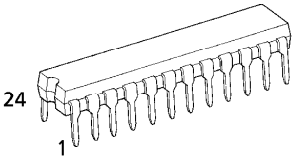
The selected output is enabled by a low on the inhibit input (INHIBIT). A binary code stored in the four input latches (A thru D) is decided and provides a high level at the corresponding one of sixteen outputs. When the INHIBIT is held low, all outputs are kept low however, the latch function is available.

The data applied to the data inputs are transferred to the outputs of latches when the strobe input is held high. When the strobe input is taken low, the data is retained at the output of the latches.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

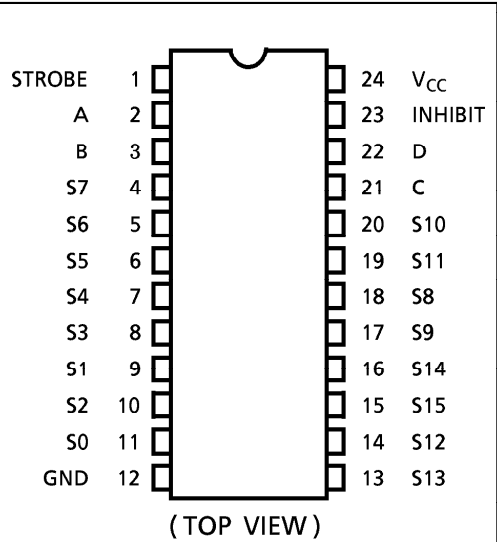
FEATURES :

- High Speed..... $t_{pd} = 18ns (typ.)$ at $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A (Max.)$ at $T_a = 25^{\circ}C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC} (Min.)$
- Output Drive Capability..... 10 LSTTL Loads
- Symmetrical Output Impedance... $|I_{OH}| = I_{OL} = 4mA (Min.)$
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range.... $V_{CC} (opr.) = 2V \sim 6V$
- Pin and Function Compatible with 4514B

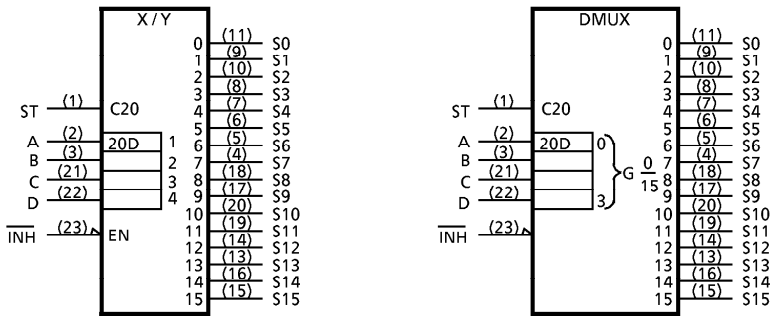


P (DIP24-P-300-2.54)
Weight : 1.50g (Typ.)

PIN ASSIGNMENT



IEC LOGIC SYMBOL



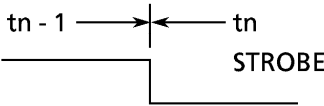
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TRUTH TABLE

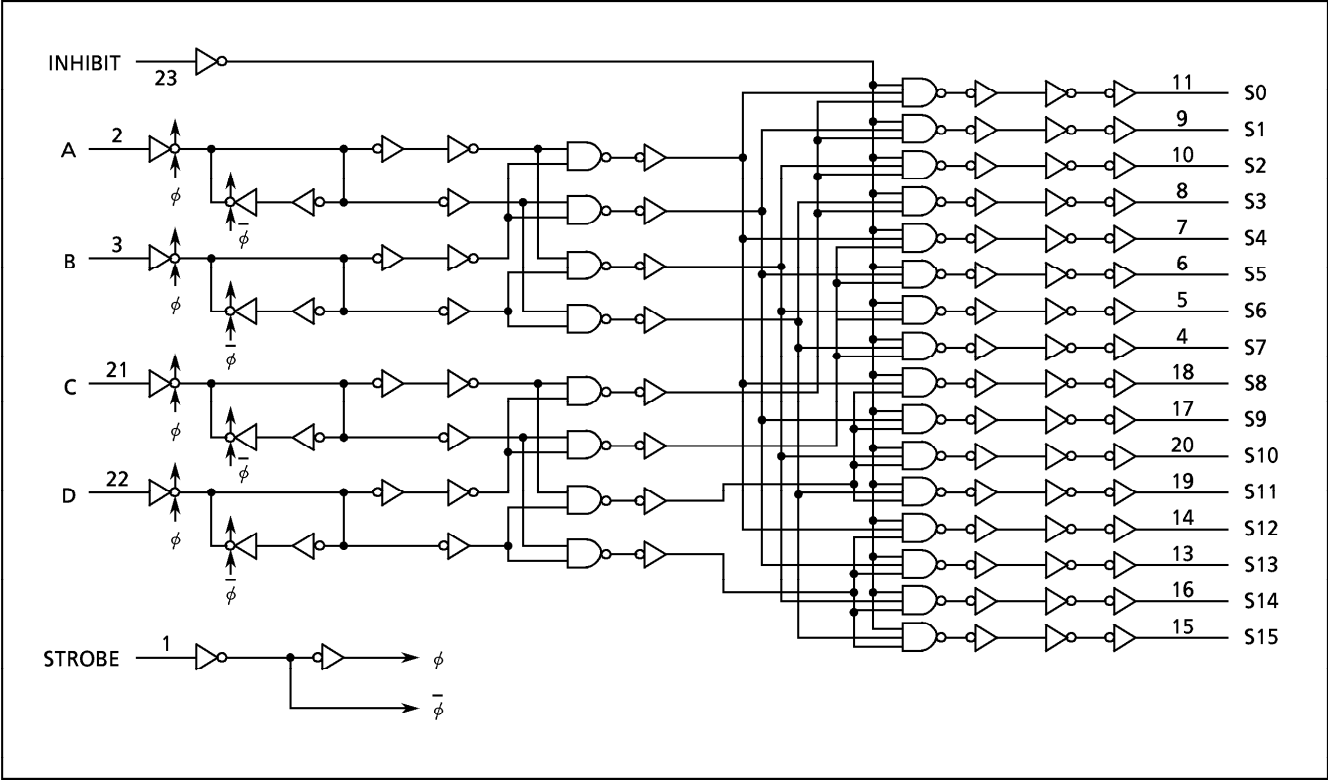
INPUTS					SELECTED OUTPUT
INHIBIT	A	B	C	D	"H"
L	L	L	L	L	S0
L	H	L	L	L	S1
L	L	H	L	L	S2
L	H	H	L	L	S3
L	L	L	H	L	S4
L	H	L	H	L	S5
L	L	H	H	L	S6
L	H	H	H	L	S7
L	L	L	L	H	S8
L	H	L	L	H	S9
L	L	H	L	H	S10
L	H	H	L	H	S11
L	L	L	H	H	S12
L	H	L	H	H	S13
L	L	H	H	H	S14
L	H	H	H	H	S15
H	X	X	X	X	ALL OUTPUT "L"

- X : Don't Care
- STROBE = "H" ; REFER TO TRUTH TABLE
- STROBE = "H"



Data at the negative going transition of strobe shall be provided on each output while strobe is held low.

SYSTEM DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5 \sim 7$	V
DC Input Voltage	V_{IN}	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} /Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	500 (DIP)*	mW
Storage Temperature	T_{stg}	$-65 \sim 150$	°C

*500mW in the range of $T_a = -40^\circ\text{C} \sim 65^\circ\text{C}$. From $T_a = 65^\circ\text{C}$ to 85°C a derating factor of $-10\text{mW}/^\circ\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	$2 \sim 6$	V
Input Voltage	V_{IN}	$0 \sim V_{CC}$	V
Output Voltage	V_{OUT}	$0 \sim V_{CC}$	V
Operating Temperature	T_{opr}	$-40 \sim 85$	°C
Input Rise and Fall Time	t_r, t_f	$0 \sim 1000 (V_{CC} = 2.0\text{V})$ $0 \sim 500 (V_{CC} = 4.5\text{V})$ $0 \sim 400 (V_{CC} = 6.0\text{V})$	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \sim 85^\circ\text{C}$		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
High - Level Input Voltage	V_{IH}		2.0	1.50	—	—	1.50	—	V
			4.5	3.15	—	—	3.15	—	
			6.0	4.20	—	—	4.20	—	
Low - Level Input Voltage	V_{IL}		2.0	—	—	0.50	—	0.50	V
			4.5	—	—	1.35	—	1.35	
			6.0	—	—	1.80	—	1.80	
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20\mu\text{A}$	2.0	1.9	2.0	—	1.9	V
			4.5	4.4	4.5	—	4.4	—	
			6.0	5.9	6.0	—	5.9	—	
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	—	4.13	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	—	5.63	
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 20\mu\text{A}$	2.0	—	0.0	0.1	—	V
			4.5	—	0.0	0.1	—	0.1	
			6.0	—	0.0	0.1	—	0.1	
			$I_{OL} = 4 \text{ mA}$	4.5	—	0.17	0.26	—	
			$I_{OL} = 5.2 \text{ mA}$	6.0	—	0.18	0.26	—	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC} \text{ or GND}$	6.0	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC} \text{ or GND}$	6.0	—	—	4.0	—	40.0	

TIMING REQUIREMENTS (Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			Ta = -40~85°C	UNIT
			V _{CC} (V)	TYP.	LIMIT	LIMIT	
Minimum Pulse Width (STROBE)	$t_{W(H)}$		2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum Set-up Time (DATA)	t_s		2.0	—	50	65	
			4.5	—	10	13	
			6.0	—	9	11	
Minimum Hold Time (DATA)	t_h		2.0	—	5	5	
			4.5	—	5	5	
			6.0	—	5	5	

AC ELECTRICAL CHARACTERISTICS (C_L = 15pF, V_{CC} = 5V, Ta = 25°C, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}		—	4	8	ns
Propagation Delay Time (DATA—Sn)	t_{pLH} t_{pHL}		—	18	30	
Propagation Delay Time (STROBE—Sn)	t_{pLH} t_{pHL}		—	20	30	
Propagation Delay Time (INHIBIT—Sn)	t_{pLH} t_{pHL}		—	16	30	

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, Input $t_r = t_f = 6\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	Ta = 25°C			Ta = −40~85°C		UNIT
				MIN.	TYP.	MAX.	MIN.	MAX.	
Output Transition Time	t _{TLH} t _{THL}		2.0	—	30	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation Delay Time (DATA—Sn)	t _{pLH} t _{pHL}		2.0	—	65	175	—	220	
			4.5	—	22	35	—	44	
			6.0	—	19	30	—	37	
Propagation Delay Time (STROBE—Sn)	t _{pLH} t _{pHL}		2.0	—	75	175	—	220	
			4.5	—	24	35	—	44	
			6.0	—	20	30	—	37	
Propagation Delay Time (INHIBIT—Sn)	t _{pLH} t _{pHL}		2.0	—	60	175	—	220	
			4.5	—	20	35	—	44	
			6.0	—	17	30	—	37	
Input Capacitance	C _{IN}			—	5	10	—	10	pF
Power Dissipation Capacitance	C _{PD} (1)			—	61	—	—	—	

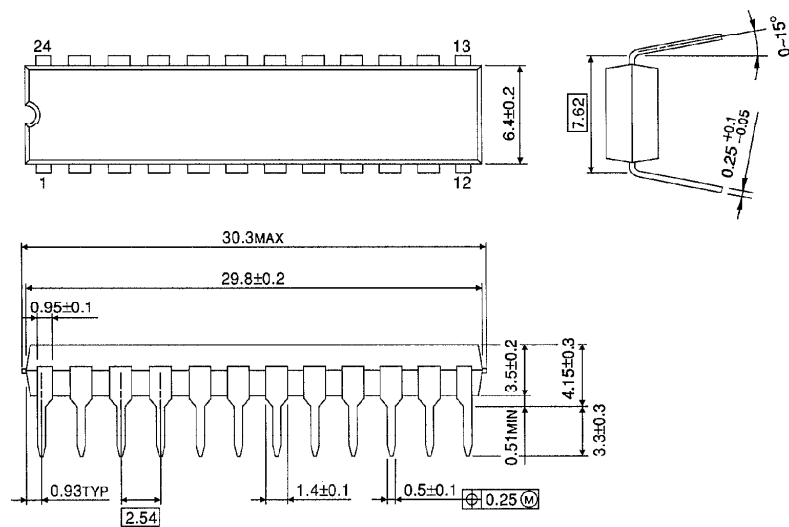
Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

DIP 24PIN OUTLINE DRAWING (DIP24-P-300-2.54)

Unit in mm



Weight : 1.50g (Typ.)